

# 74HC2G34-Q100; 74HCT2G34-Q100

## Dual buffer gate

Rev. 2 — 4 November 2013

Product data sheet

## 1. General description

The 74HC2G34-Q100; 74HCT2G34-Q100 is a dual buffer. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$
- Input levels:
  - ◆ For 74HC2G34-Q100: CMOS level
  - ◆ For 74HCT2G34-Q100: TTL level
- Wide supply voltage range from 2.0 V to 6.0 V
- Complies with JEDEC standard no. 7A
- High noise immunity
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V ( $C = 200\text{ pF}$ ,  $R = 0\text{ }\Omega$ )
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times

## 3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC2G34GW-Q100	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	SC-88	plastic surface-mounted package; 6 leads	SOT363
74HCT2G34GW-Q100				
74HC2G34GV-Q100	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457
74HCT2G34GV-Q100				



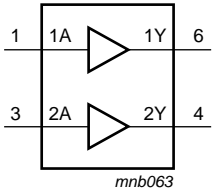
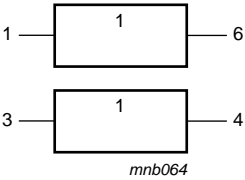
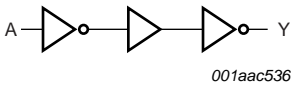
## 4. Marking

Table 2. Marking

Type number	Marking code <sup>[1]</sup>
74HC2G34GW-Q100	PA
74HCT2G34GW-Q100	UA
74HC2G34GV-Q100	P34
74HCT2G34GV-Q100	U34

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

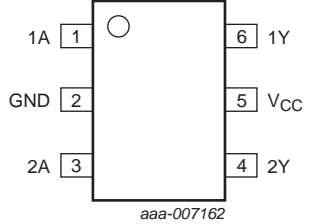
## 5. Functional diagram

 <p><b>Fig 1. Logic symbol</b></p>	 <p><b>Fig 2. IEC logic symbol</b></p>	 <p><b>Fig 3. Logic diagram (one gate)</b></p>
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## 6. Pinning information

### 6.1 Pinning

**74HC2G34-Q100**  
**74HCT2G34-Q100**



**Fig 4. Pin configuration**

## 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V <sub>CC</sub>	5	supply voltage
1Y	6	data output

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

Input	Output
nA	nY
L	L
H	H

[1] H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	[1]	±20	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	[1]	±20	mA
I <sub>O</sub>	output current	V <sub>O</sub> = -0.5 V to V <sub>CC</sub> + 0.5 V	[1]	±25	mA
I <sub>CC</sub>	supply current		[1]	+50	mA
I <sub>GND</sub>	ground current		[1]	-50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation		[2]	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 and SC-74 packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Type 74HC2G34-Q100</b>						
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
V <sub>I</sub>	input voltage		0	-	V <sub>CC</sub>	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
t <sub>r</sub>	rise time	except for Schmitt trigger inputs				
		V <sub>CC</sub> = 2.0 V	-	-	1000	ns
		V <sub>CC</sub> = 4.5 V	-	-	500	ns
		V <sub>CC</sub> = 6.0 V	-	-	400	ns
t <sub>f</sub>	fall time	except for Schmitt trigger inputs				
		V <sub>CC</sub> = 2.0 V	-	-	1000	ns
		V <sub>CC</sub> = 4.5 V	-	-	500	ns
		V <sub>CC</sub> = 6.0 V	-	-	400	ns
<b>Type 74HCT2G34-Q100</b>						
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		0	-	V <sub>CC</sub>	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
t <sub>r</sub>	rise time	except for Schmitt trigger inputs				
		V <sub>CC</sub> = 4.5 V	-	-	500	ns
t <sub>f</sub>	fall time	except for Schmitt trigger inputs				
		V <sub>CC</sub> = 4.5 V	-	-	500	ns

## 10. Static characteristics

**Table 7. Static characteristics for 74HC2G34-Q100**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V

**Table 7. Static characteristics for 74HC2G34-Q100 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = -20 \mu\text{A}; V_{CC} = 2.0 \text{ V}$	1.9	2.0	-	V
		$I_O = -20 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	4.4	4.5	-	V
		$I_O = -20 \mu\text{A}; V_{CC} = 6.0 \text{ V}$	5.9	6.0	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	V
		$I_O = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.68	5.81	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu\text{A}; V_{CC} = 2.0 \text{ V}$	-	0	0.1	V
		$I_O = 20 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	-	0	0.1	V
		$I_O = 20 \mu\text{A}; V_{CC} = 6.0 \text{ V}$	-	0	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
$I_I$	input leakage current	$V_I = \text{GND}$ or $V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	$\pm 0.1$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = \text{GND}$ or $V_{CC}; I_O = 0 \text{ A}; V_{CC} = 6.0 \text{ V}$	-	-	1.0	$\mu\text{A}$
$C_I$	input capacitance		-	1.5	-	pF
<b><math>T_{amb} = -40 \text{ }^\circ\text{C}</math> to <math>+85 \text{ }^\circ\text{C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 2.0 \text{ V}$	1.5	-	-	V
		$V_{CC} = 4.5 \text{ V}$	3.15	-	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	-	-	0.5	V
		$V_{CC} = 4.5 \text{ V}$	-	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	-	1.8	V
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = -20 \mu\text{A}; V_{CC} = 2.0 \text{ V}$	1.9	-	-	V
		$I_O = -20 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	4.4	-	-	V
		$I_O = -20 \mu\text{A}; V_{CC} = 6.0 \text{ V}$	5.9	-	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	-	-	V
		$I_O = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.63	-	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu\text{A}; V_{CC} = 2.0 \text{ V}$	-	-	0.1	V
		$I_O = 20 \mu\text{A}; V_{CC} = 4.5 \text{ V}$	-	-	0.1	V
		$I_O = 20 \mu\text{A}; V_{CC} = 6.0 \text{ V}$	-	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
$I_I$	input leakage current	$V_I = \text{GND}$ or $V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = \text{GND}$ or $V_{CC}; I_O = 0 \text{ A}; V_{CC} = 6.0 \text{ V}$	-	-	10.0	$\mu\text{A}$

**Table 7. Static characteristics for 74HC2G34-Q100 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 6.0 V	-	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	20.0	μA

**Table 8. Static characteristics for 74HCT2G34-Q100**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	4.18	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 5.5 V	-	-	±0.1	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	1.0	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A	-	-	300	μA
C <sub>I</sub>	input capacitance		-	1.5	-	pF

**Table 8. Static characteristics for 74HCT2G34-Q100 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	4.13	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 5.5 V	-	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	10.0	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A	-	-	375	μA
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 5.5 V	-	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	20.0	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A	-	-	410	μA

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 6](#).

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
<b>74HC2G34-Q100</b>									
$t_{pd}$	propagation delay	nA to nY; see <a href="#">Figure 5</a> <a href="#">[1]</a>							
		$V_{CC} = 2.0\text{ V}; C_L = 50\text{ pF}$	-	29	75	-	95	125	ns
		$V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$	-	9	15	-	19	25	ns
		$V_{CC} = 6.0\text{ V}; C_L = 50\text{ pF}$	-	8	13	-	16	20	ns
$t_t$	transition time	nY; see <a href="#">Figure 5</a> <a href="#">[2]</a>							
		$V_{CC} = 2.0\text{ V}; C_L = 50\text{ pF}$	-	18	75	-	95	125	ns
		$V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$	-	6	15	-	19	25	ns
		$V_{CC} = 6.0\text{ V}; C_L = 50\text{ pF}$	-	5	13	-	16	20	ns
$C_{PD}$	power dissipation capacitance	$V_I = \text{GND to } V_{CC}$ <a href="#">[3]</a>	-	10	-	-	-	-	pF
<b>74HCT2G34-Q100</b>									
$t_{pd}$	propagation delay	nA to nY; see <a href="#">Figure 5</a> <a href="#">[1]</a>							
		$V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$	-	10	18	-	23	29	ns
$t_t$	transition time	nY; see <a href="#">Figure 5</a> <a href="#">[2]</a>							
		$V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$	-	6	15	-	19	25	ns
$C_{PD}$	power dissipation capacitance	$V_I = \text{GND to } V_{CC} - 1.5\text{ V}$ <a href="#">[3]</a>	-	9	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$

[2]  $t_t$  is the same as  $t_{TLH}$  and  $t_{THL}$

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

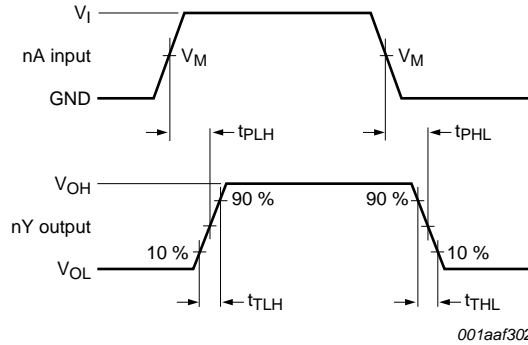
$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.



12. Waveforms



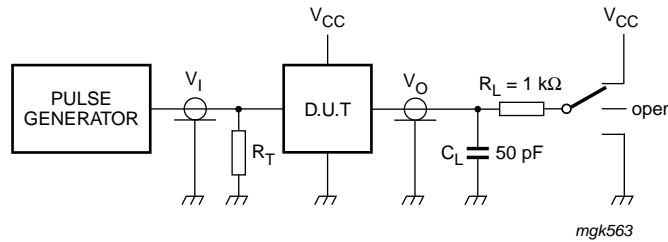
Measurement points are given in [Table 10](#).

$V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 5. The data input (nA) to output (nY) propagation delays and output transition times**

**Table 10. Measurement points**

Type	Input			Output
	$V_M$	$V_I$	$t_r = t_f$	$V_M$
74HC2G34-Q100	$0.5V_{CC}$	GND to $V_{CC}$	6.0 ns	$0.5V_{CC}$
74HCT2G34-Q100	1.3 V	GND to 3.0 V	6.0 ns	1.3 V



Test data is given in [Table 11](#).

Definitions test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

**Fig 6. Test circuit for measuring switching times**

**Table 11. Test data**

Type	Input		Test
	$V_I$	$t_r, t_f$	$t_{PHL}, t_{PLH}$
74HC2G34-Q100	GND to $V_{CC}$	6 ns	open
74HCT2G34-Q100	GND to 3.0 V	6 ns	open

13. Package outline

Plastic surface-mounted package; 6 leads

SOT363

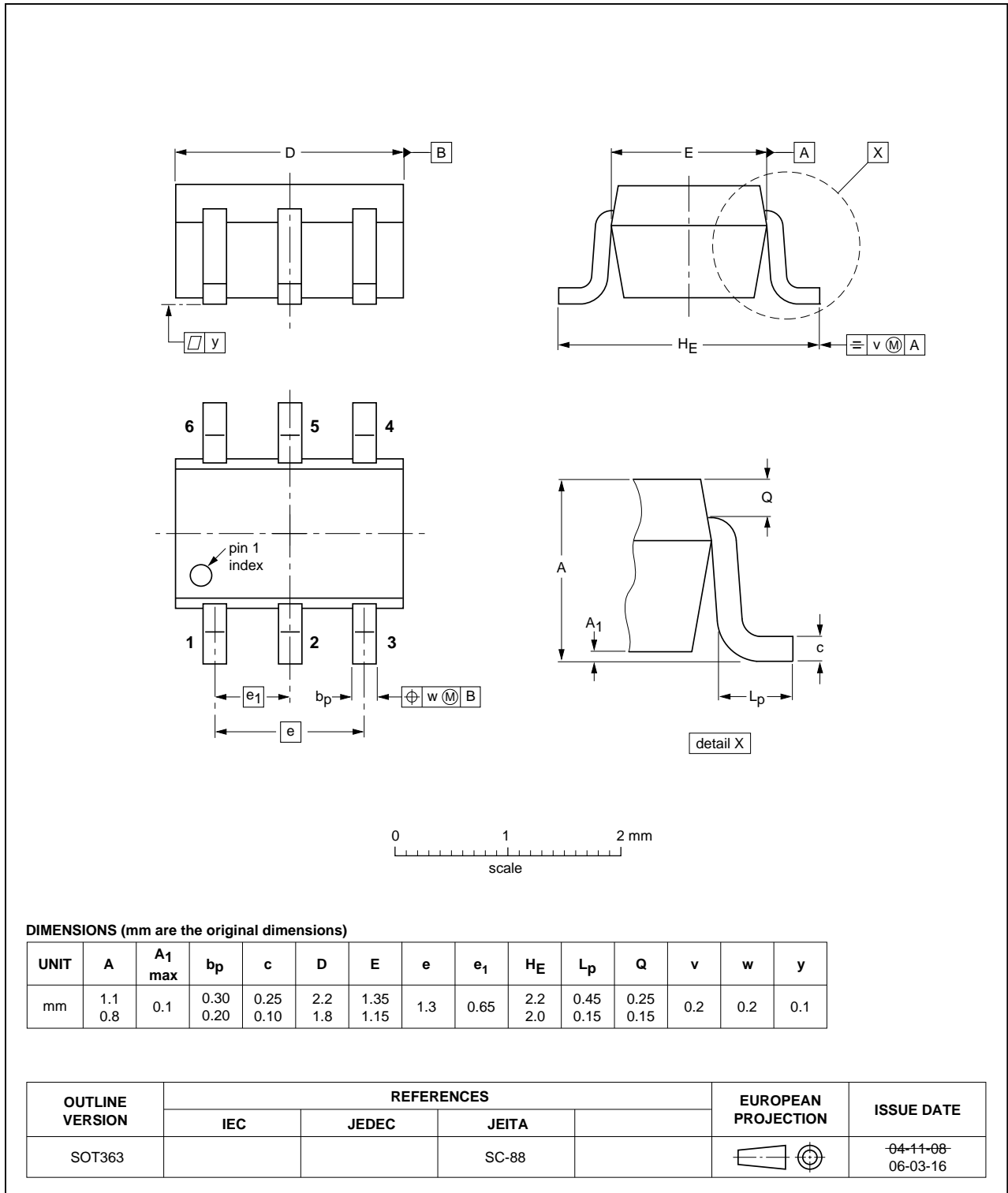


Fig 7. Package outline SOT363 (SC-88)

Plastic surface-mounted package (TSOP6); 6 leads

SOT457

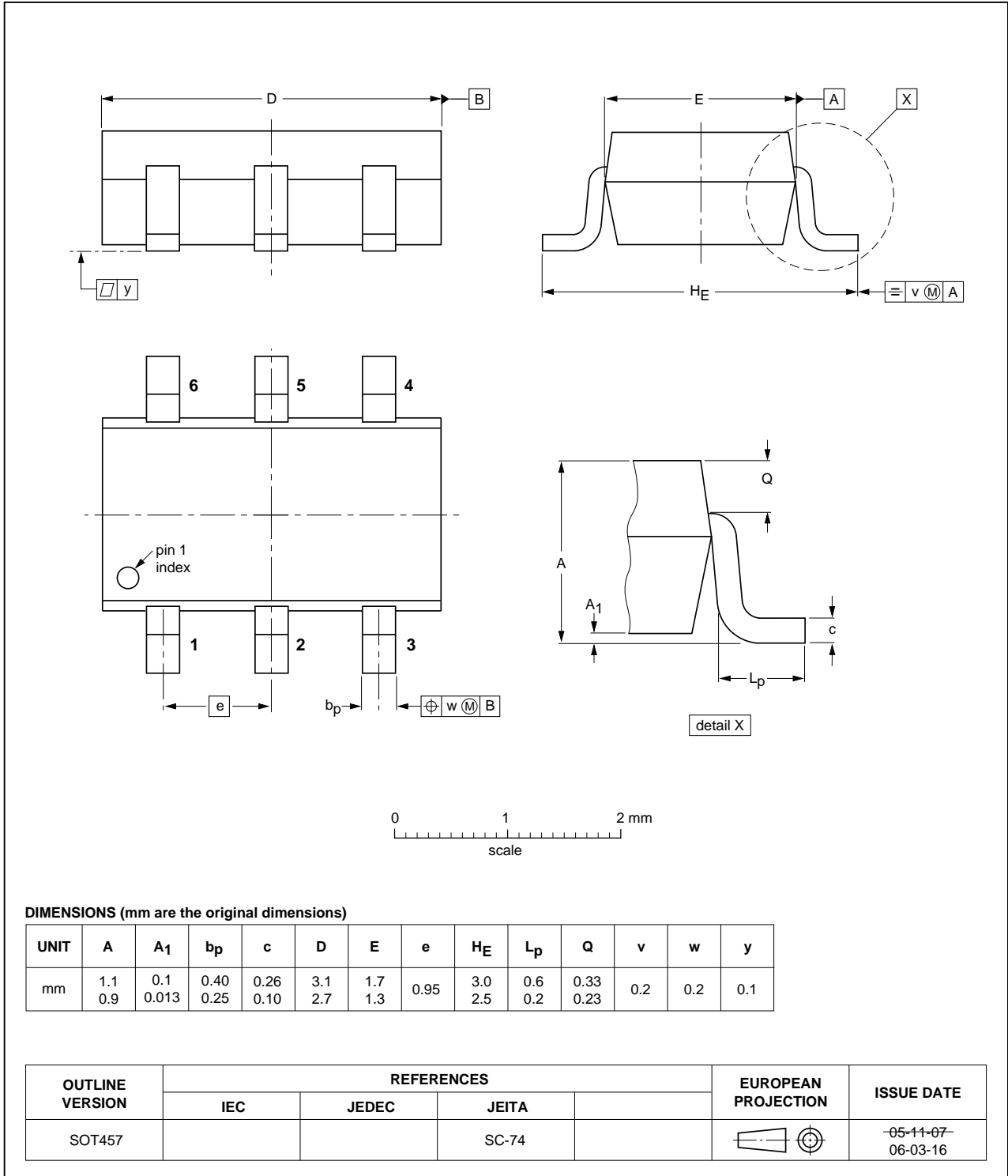


Fig 8. Package outline SOT457 (SC-74)

## 14. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
DUT	Device Under Test

## 15. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT2G34_Q100 v.2	20131104	Product data sheet	-	74HC_HCT2G34_Q100 v.1
Modifications:	• Added type number 74HC2G34GW and 74HCT2G34GW (SOT363)			
74HC_HCT2G34_Q100 v.1	20130417	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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